NSN 5962-01-277-3324

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View Online at https://aerobasegroup.com/nsn/5962-01-277-3324

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 ir	nches and 0.310 inches
Body Height:	
0.185 inches	
Maximum Powe	r Dissipation Rating:
500.0 milliwatts	
Operating Temp	purature Range:
-55.0/+125.0 deg	rees celsius
Storage Tempu	rature Range:
-65.0/+150.0 deg	rees celsius
Features Provid	ed:
Hermetically seal	led and burn in and programmable and 3-state output
Inclosure Mater	ial:
Ceramic	
Inclosure Config	guration:
Dual-in-line	
Output Logic Fo	orm:
Transistor-transis	stor logic
Input Circuit Pat	ttern:
6 input	
Case Outline So	purce And Designator:
D-2 mil-m-38510	
Terminal Surfac	e Treatment:
Solder	
Voltage Rating	And Type Per Characteristic:
7.0 volts power	source
Time Rating Per	Chacteristic:
70.00 nanosecor	nds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	Туре:
Rom	
Memory Capaci	ty:
Unknown	
Test Data Docu	ment:
96906-mil-std-88	3 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type A	And Quantity:
16 printed circuit	
Shelf Life:	
N/a	

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Demilitarization:

Yes - demil/mli

Fiig:

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